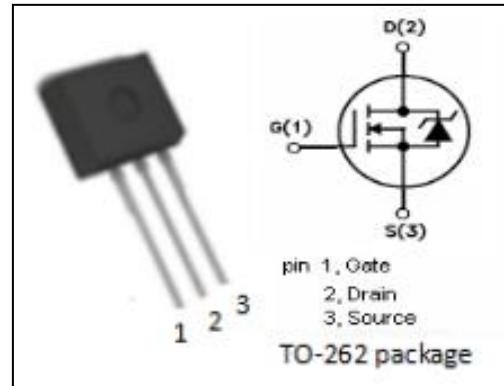


**isc N-Channel MOSFET Transistor****IRFZ24NLPbF****• FEATURES**

- With TO-262(DPAK) packaging
- Surface mount
- High speed switching
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operationz

**• APPLICATIONS**

- Switching applications

**• ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DSS}$	Drain-Source Voltage	55	V
$V_{GSS}$	Gate-Source Voltage	$\pm 20$	V
$I_D$	Drain Current-Continuous@ $T_c=25^\circ\text{C}$ $T_c=100^\circ\text{C}$	17 12	A
$I_{DM}$	Drain Current-Single Pulsed	68	A
$P_D$	Total Dissipation	45	W
$T_j$	Operating Junction Temperature	-55~175	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-55~175	$^\circ\text{C}$

**• THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	3.3	$^\circ\text{C}/\text{W}$
$R_{th(ch-a)}$	Channel-to-ambient thermal resistance	40	$^\circ\text{C}/\text{W}$

## isc N-Channel MOSFET Transistor

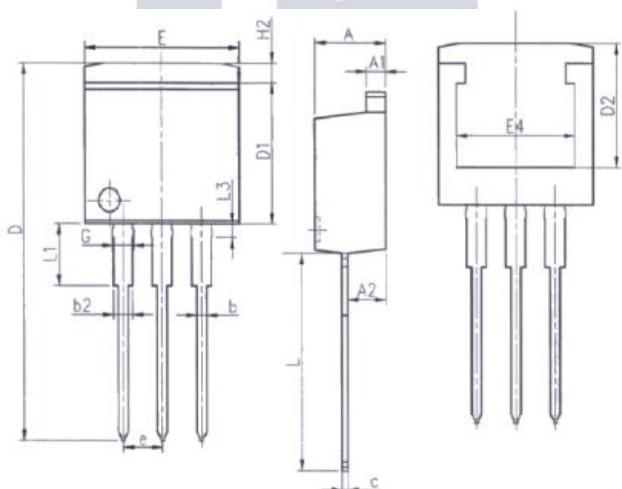
IRFZ24NLPbF

## ELECTRICAL CHARACTERISTICS

 $T_c=25^\circ\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
$\text{BV}_{\text{DSS}}$	Drain-Source Breakdown Voltage	$\text{V}_{\text{GS}}=0\text{V}; \text{I}_D= 0.25\text{mA}$	55			V
$\text{V}_{\text{GS(th)}}$	Gate Threshold Voltage	$\text{V}_{\text{DS}}=\pm 20\text{V}; \text{I}_D=0.25\text{mA}$	2		4	V
$\text{R}_{\text{DS(on)}}$	Drain-Source On-Resistance	$\text{V}_{\text{GS}}= 10\text{V}; \text{I}_D=10\text{A}$			70	$\text{m}\Omega$
$\text{I}_{\text{GSS}}$	Gate-Source Leakage Current	$\text{V}_{\text{GS}}= \pm 20\text{V}; \text{V}_{\text{DS}}= 0\text{V}$			$\pm 0.1$	$\mu\text{A}$
$\text{I}_{\text{DSS}}$	Drain-Source Leakage Current	$\text{V}_{\text{DS}}= 55\text{V}; \text{V}_{\text{GS}}= 0\text{V} @ \text{T}_c=25^\circ\text{C}$ $\text{T}_c=125^\circ\text{C}$			20 250	$\mu\text{A}$
$\text{V}_{\text{SDF}}$	Diode forward voltage	$\text{I}_{\text{SD}}=10\text{A}, \text{V}_{\text{GS}} = 0 \text{ V}$			1.3	V

## DIMENSIONAL DRAWING



Unit: mm		
Symbol	Min.	Max.
A	4.37	4.77
A1	1.22	1.42
A2	2.47	2.87
b	0.70	0.97
b2	1.17	1.42
c	0.28	0.53
D	23.20	24.02
D1	8.38	8.90
D2	6.00	-

Unit: mm		
Symbol	Min.	Max.
E	9.90	10.39
E4	7.30	-
e	2.54BSC	
G	1.25	1.50
H2	-	1.31
L	13.34	14.10
L1	3.30	4.06
L3	0.95	1.15

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